

# CCD Vertex Detector and Beam Background

Yasuhiro Sugimoto  
KEK  
May 1. 1999@LCWS99

- Study of CCD sensors
  - Spatial resolution - Beam test results
  - Radiation hardness test
- Beam background and  $R_{\min}$

# Study of CCD Sensors

## **R&D goal :**

**Normal temperature (> 0 deg.) operation of CCD vertex detector in the environment of JLC experiment**

- Avoid thermal distortion of wafers**
- Free space (no cryostat) for forward-tracker and beam monitors**

## **Collaboration:**

**KEK**

**Saga Univ.**

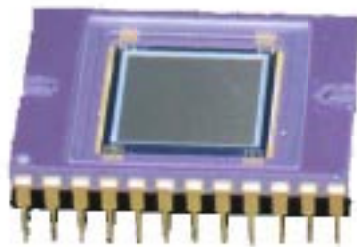
**Tohoku Univ.**

**Niigata Univ.**

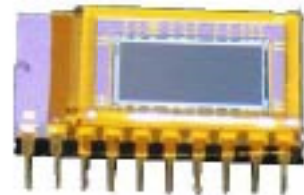
**Toyama Nat. Col. of Maritime Tech.**

## CCD samples

**Hamamatsu  
S5466**



**EEV  
CCD02-06**



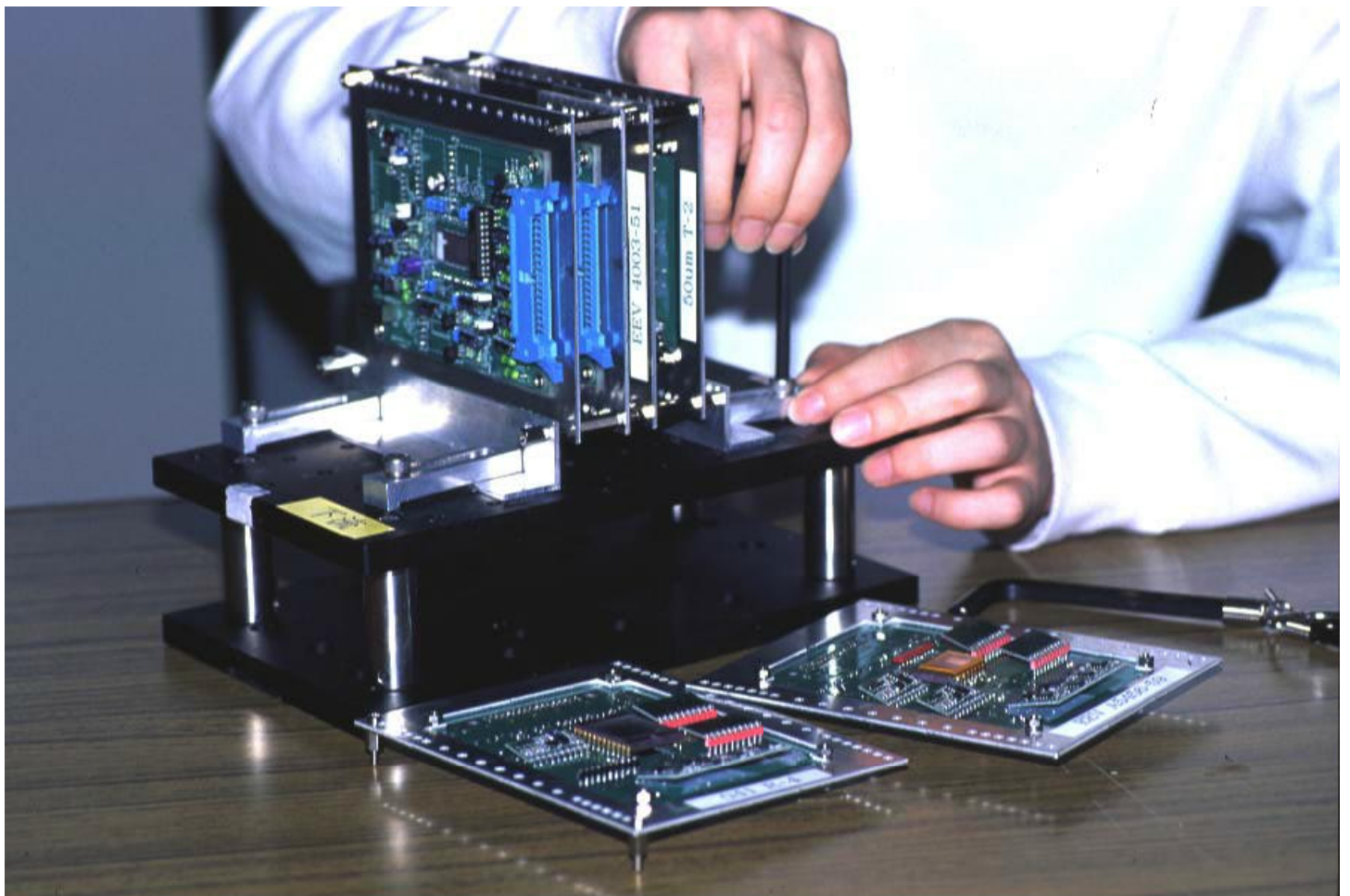
<b>Pixel size</b>	<b>24 <math>\mu\text{m}</math></b>	<b>22 <math>\mu\text{m}</math></b>
<b>Epi. thickness</b>	<b>10 / 50 <math>\mu\text{m}</math></b>	<b>20 <math>\mu\text{m}</math></b>
<b>Gate oxide</b>	<b><math>\text{SiO}_2</math></b>	<b><math>\text{SiO}_2\text{-Si}_3\text{N}_4</math></b>
<b>Clock</b>	<b>2-phase</b>	<b>3-phase</b>
<b>Gain</b>	<b>2 <math>\mu\text{V}/\text{e}</math></b>	<b>1 <math>\mu\text{V}/\text{e}</math></b>
<b>Mode</b>	<b>Inverted</b>	<b>Inverted</b>

( Surface current is strongly suppressed with inverted mode)

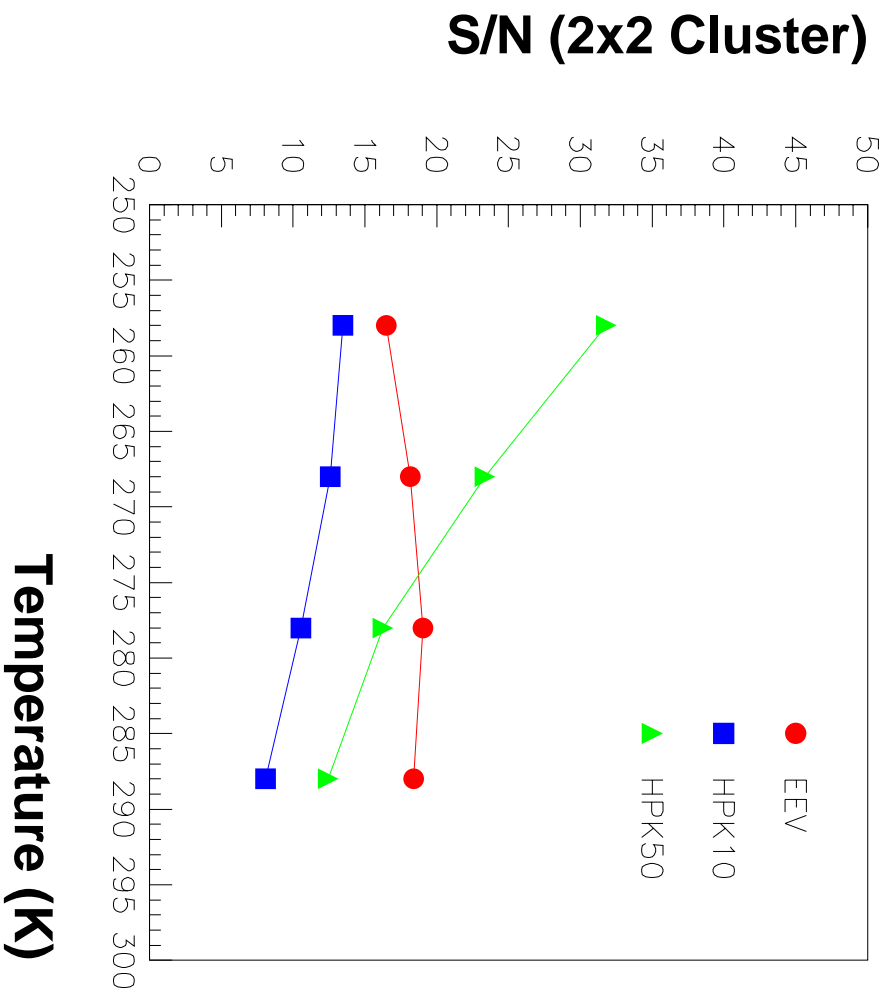
## Study of spatial resolution

### Test beam experiment:

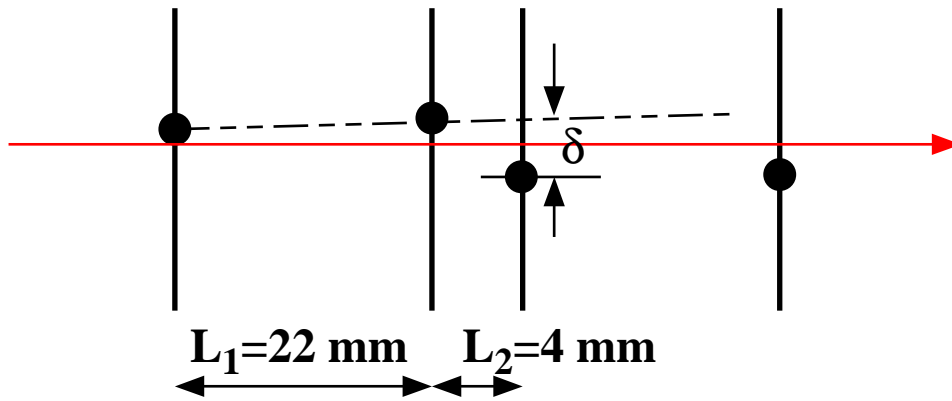
- 0.5, 0.7, 1.0 and 2.0 GeV/c p- beam
- Incident angles of 0, 45, and 60 degrees
- Operation temp. -15 ~ +15 degrees
- Readout cycle; 3 sec (= PS machine cycle)
- 4 layers of CCD samples
  - 1st, 2nd, 4th layers: HPK 10 $\mu$ m
  - 3ed layer: HPK 10 $\mu$ m, 50 $\mu$ m, EEV 20 $\mu$ m



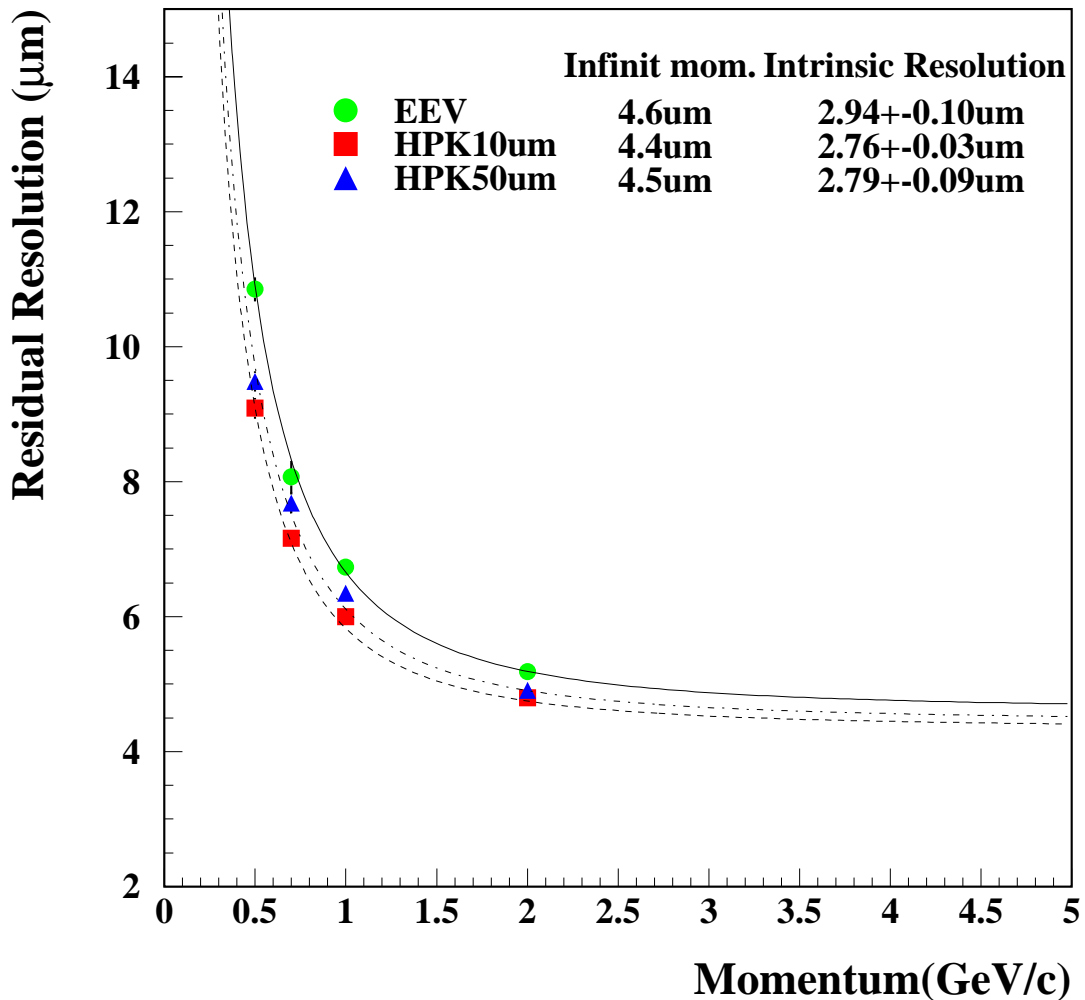
# S/N ratio



# Spatial Resolution



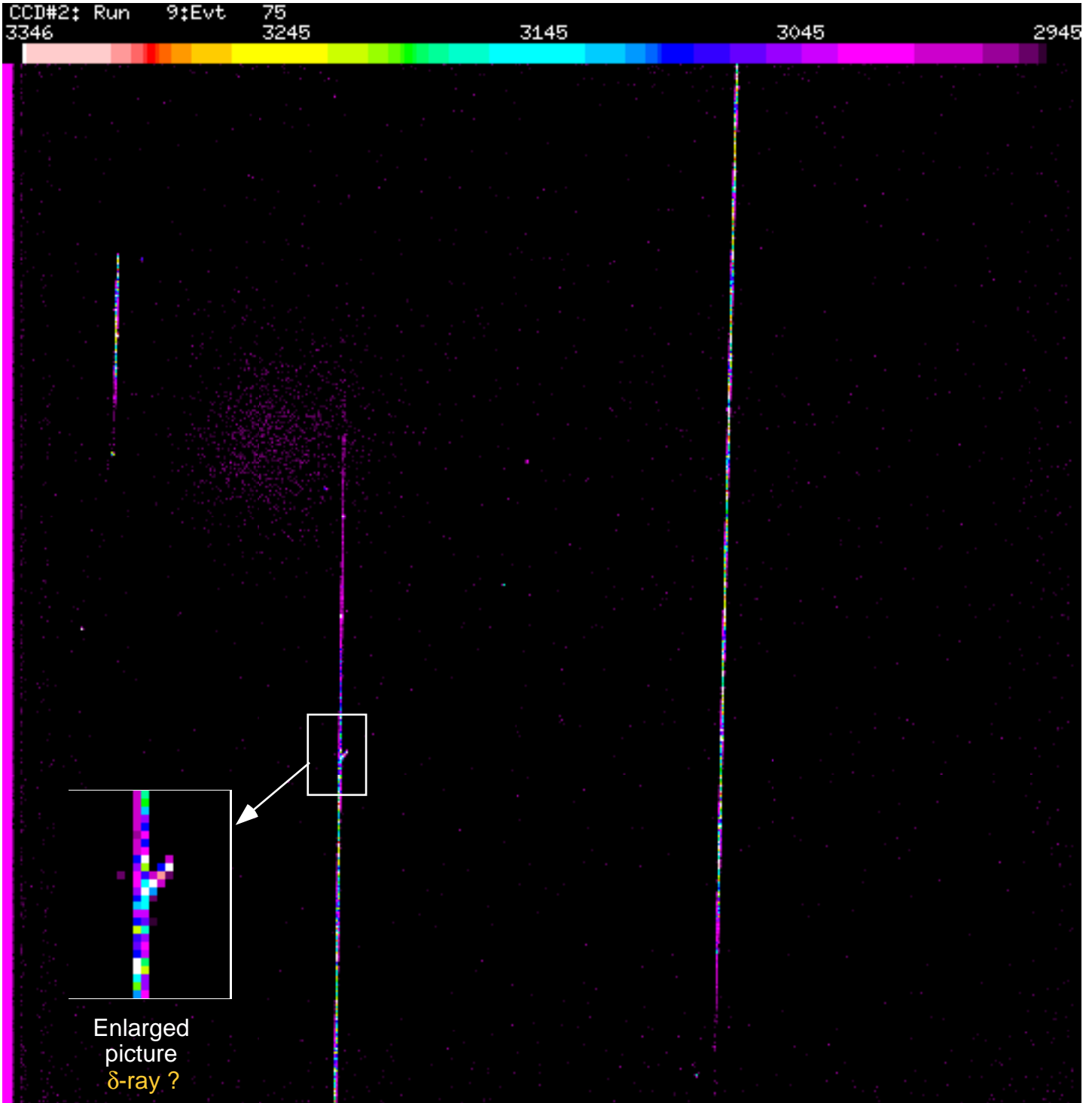
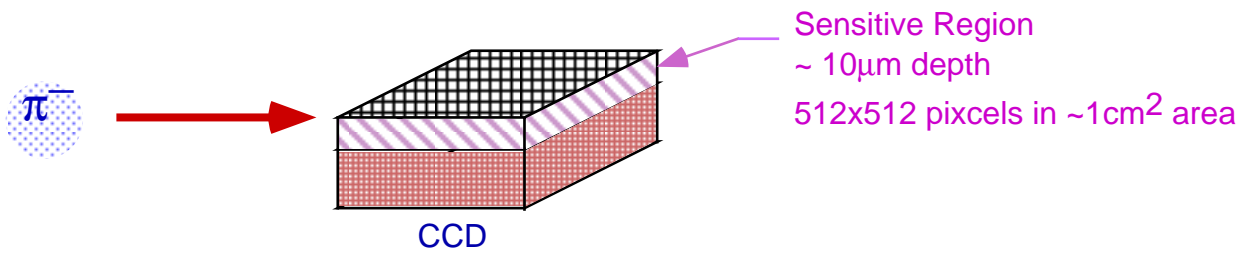
## Resolution at 258K



$$\delta^2 = 2\sigma^2(L_1^2 + L_2^2 + L_1L_2)/L_1^2 + (\theta_{MS}L_2)^2$$

( $\delta$  : residual resolution,  $\sigma$  : intrinsic resolution)

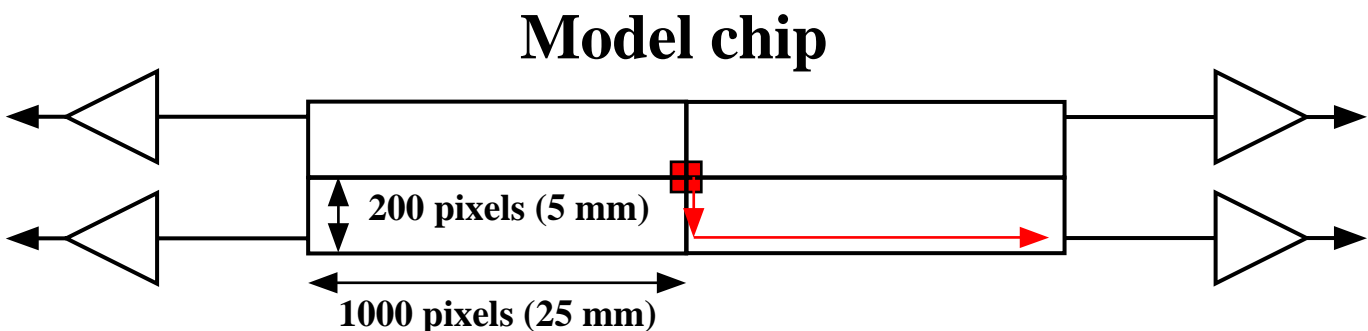
# Particle trajectories seen by a CCD sensor



# Radiation hardness test

## Radiation damage on CCD sensors

- Increase of dark current (surface, bulk)
- Shift of operation voltage (surface)
- Increase of charge transfer inefficiency (CTI) (bulk)



### Requirement for CTI:

$$\text{Vertical CTI} < 1 \cdot 10^{-3}: \quad (1 - 0.001)^{200} = 0.82$$

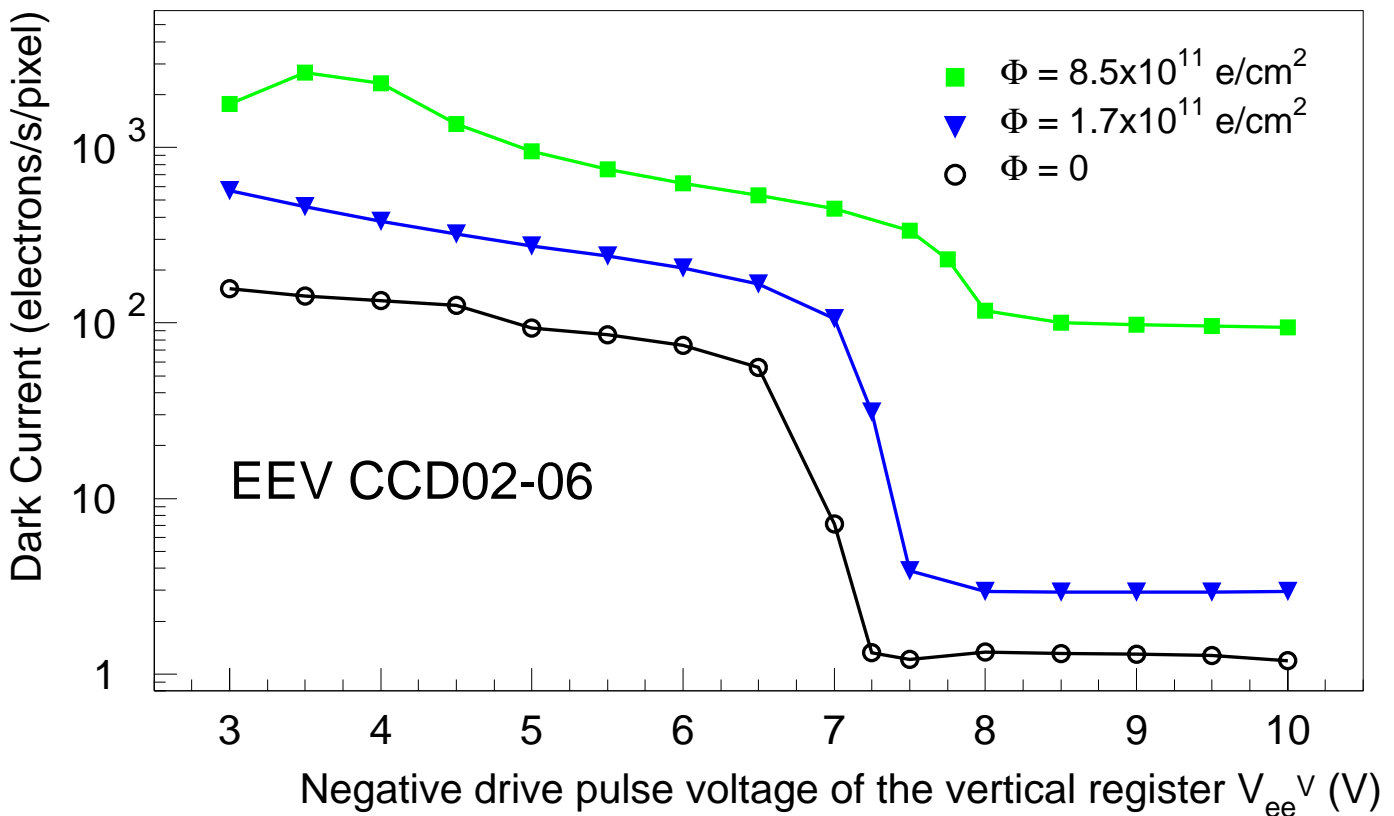
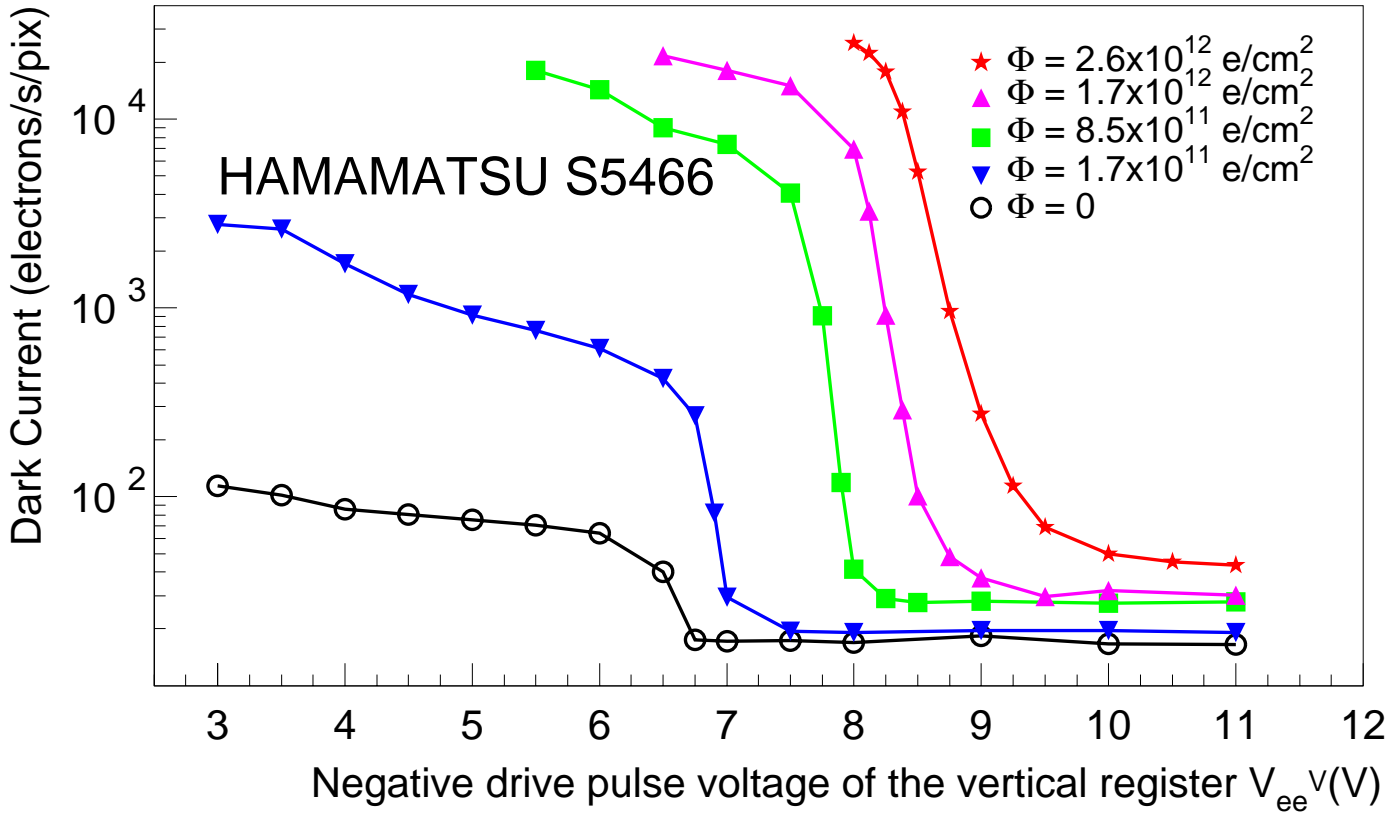
$$\text{Horizontal CTI} < 0.2 \cdot 10^{-3}: \quad (1 - 0.0002)^{1000} = 0.82$$

$$\rightarrow \text{Worst case: } 0.82 \cdot 0.82 = 0.67$$

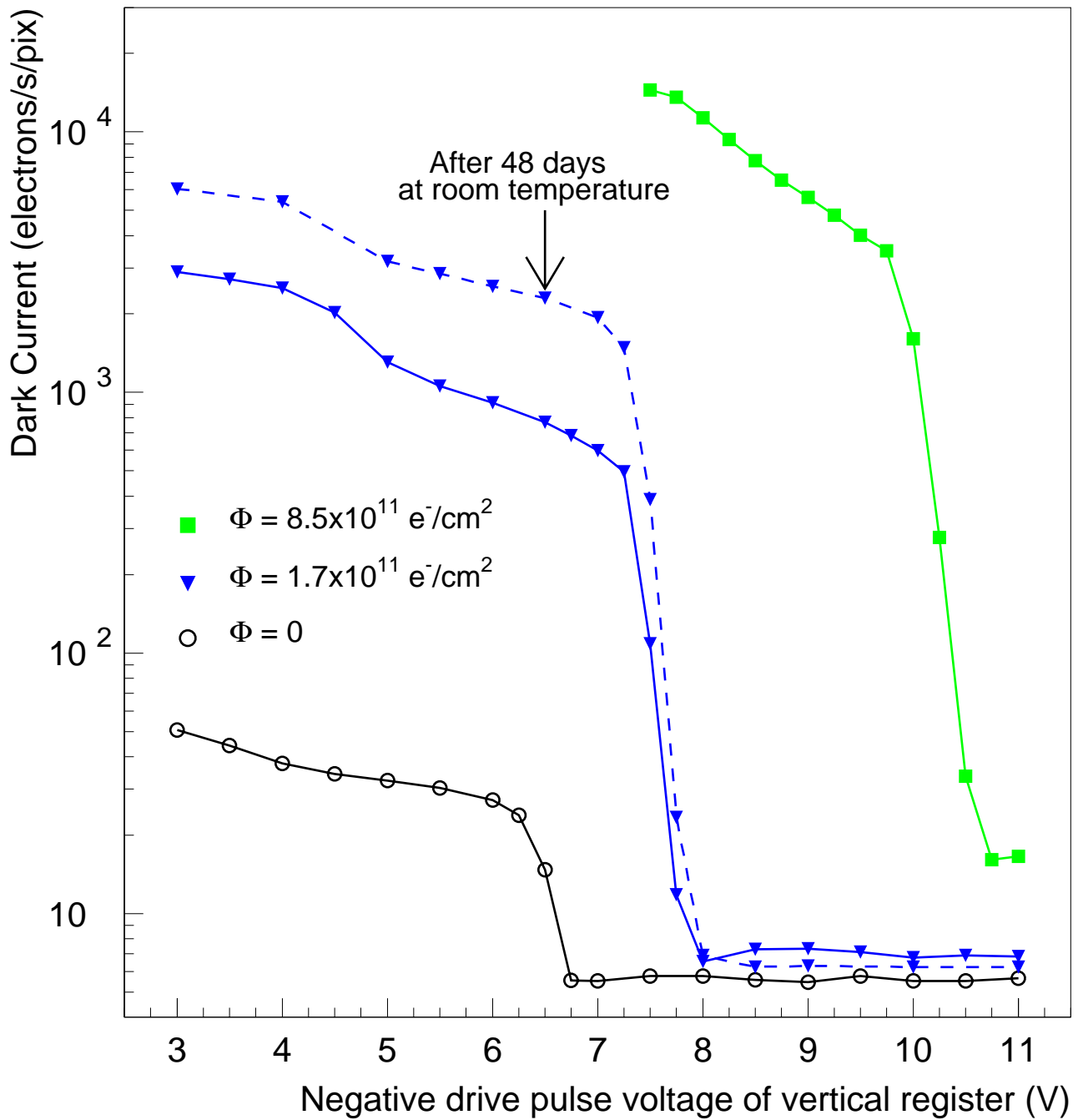


# Electron damage - $^{90}\text{Sr}$

Dark current at -30 deg. (all pins grounded during irradiation)

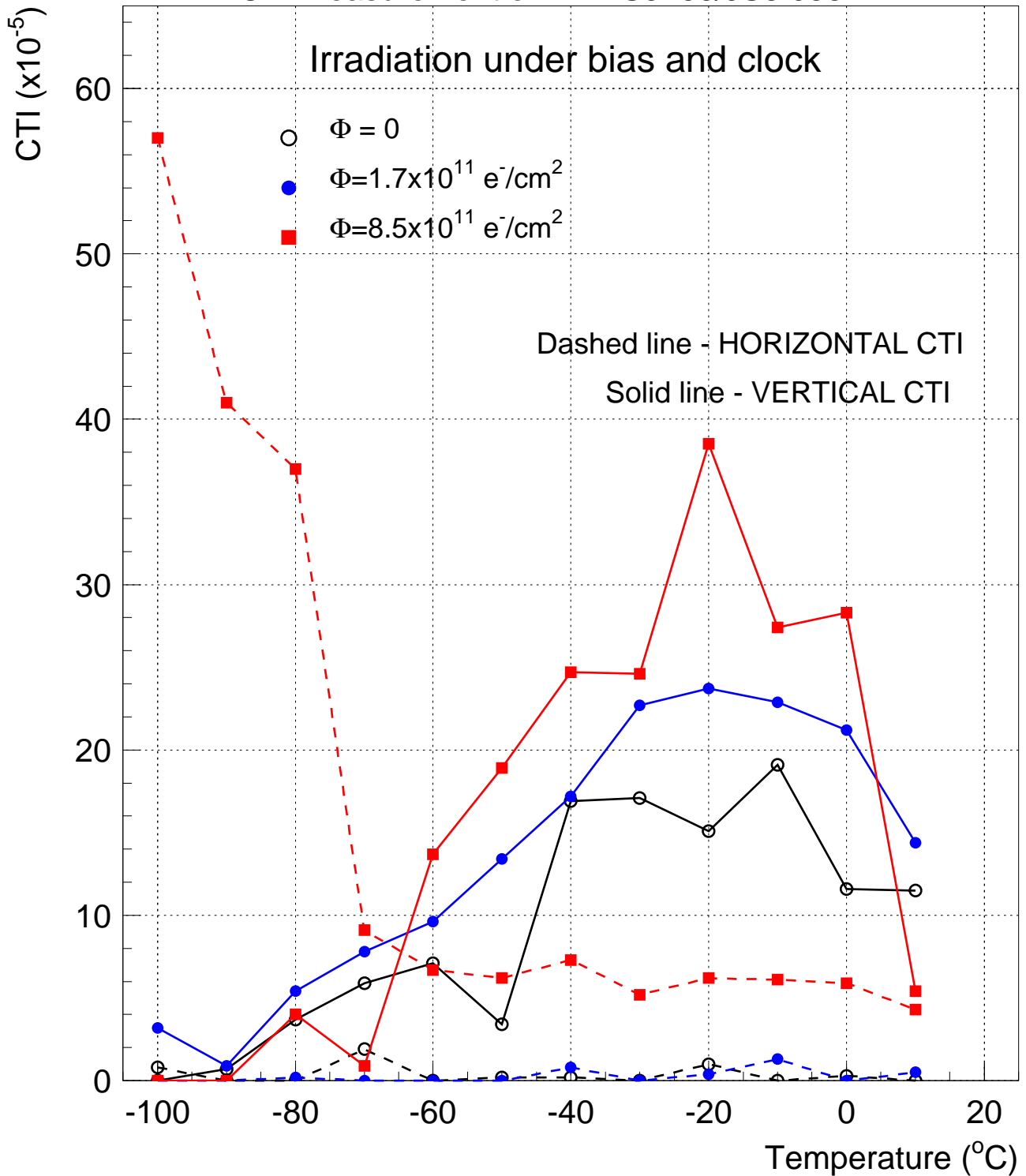


### Dark current at -30 deg. (with clocking during irradiation)



**Note that surface damage by MIP electrons is 1/3 smaller than  $^{90}\text{Sr}$  electrons**

### CTI Measurement of HPK S5466/JS8 053

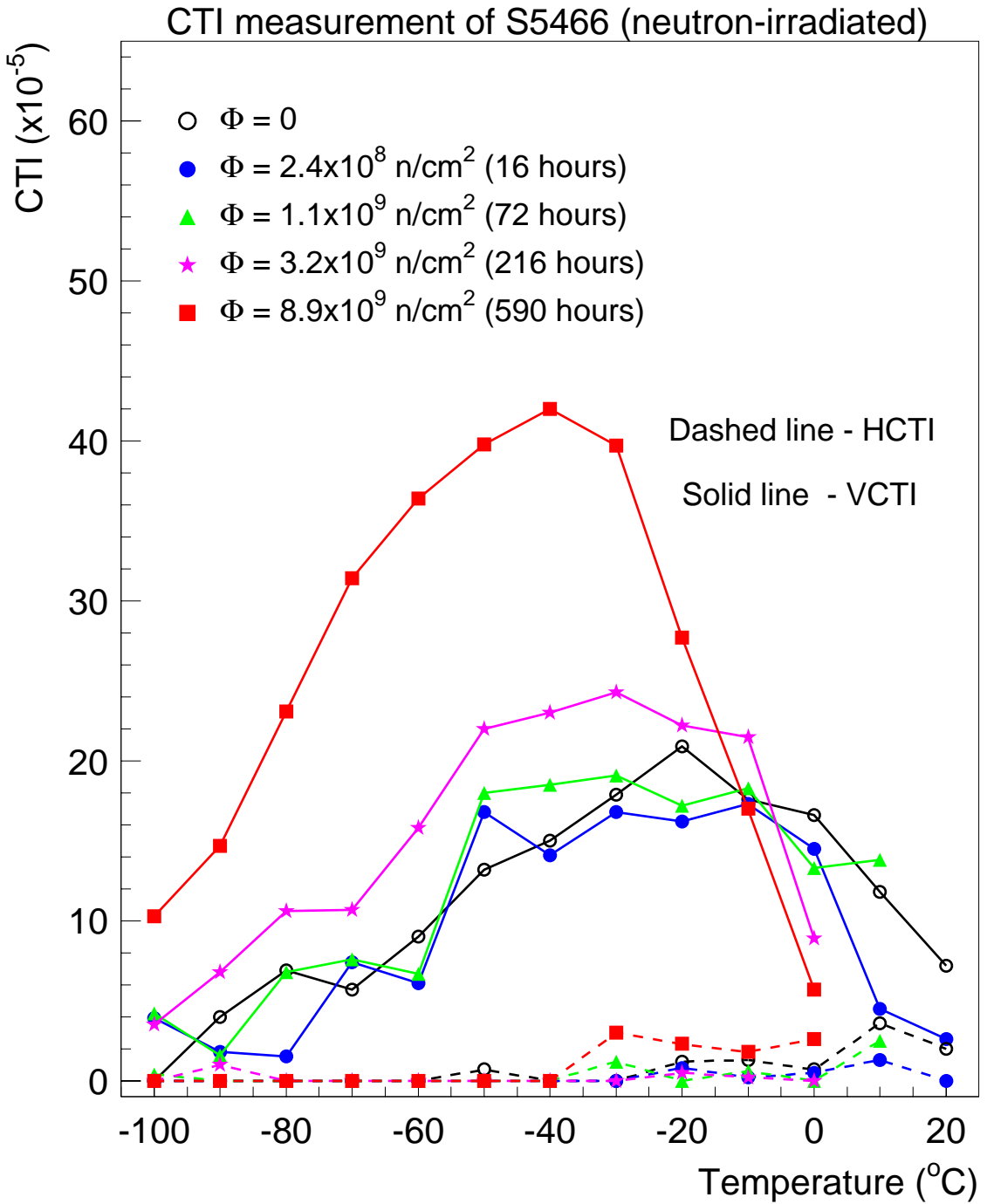


-> Limit ~  $1.5 \times 10^{12} \text{ e}/\text{cm}^2$

Note that bulk damage by MIP electrons is stronger (few times but less than x10) than low energy (~1 MeV) electrons.

-> Limit >  $1.5 \times 10^{11} \text{ e(MIP)}/\text{cm}^2$

# Neutron damage - $^{252}\text{Cf}$



-> Limit  $\sim 1.5 \times 10^{10} \text{ n/cm}^2$

# Beam background and $R_{\min}$ of the vertex detector

**Neutron background :  $1 \cdot 10^9$  /cm<sup>2</sup>y -> OK**

**$e^+e^-$  pair background :  $1.5 \cdot 10^{11}$  /cm<sup>2</sup>y @2.4cm  
-> OK**

**What about smaller R?**

**How to make  $R_{\min}$  smaller?**

**Stronger B field**

**Hardening of CCD**

- **Narrower transfer channel  
(reduce # of traps)**
- **Fat-zero charge injection  
(fill up traps)**
- **High speed operation  
(readout signal before trapped)**
- **Low temperature operation  
(suppress ejection from traps)**

# Summary

- **CCD vertex detector can achieve**
  - **S/N > 10 even at normal temp. (> 0 deg.)**
  - **Spatial resolution < 3  $\mu\text{m}$**
  - **Radiation tolerance**
    - $1.5 \cdot 10^{12} / \text{cm}^2$  for  $e^-$  from  $^{90}\text{Sr}$**
    - $1.5 \cdot 10^{10} / \text{cm}^2$  for neutrons**
    - > **CCD can be put at  $R=24$  mm in the JLC experiment**

**Several times better tolerance is anticipated with hardening technology**

**If operated at -100 degrees, 5 ~ 10 times better tolerance can be obtained**

- **To make  $R_{\min}$  of the vertex detector smaller**
  - **Stronger B field is preferable.**
  - **Otherwise, more R&D effort and/or low temperature operation is needed.**